

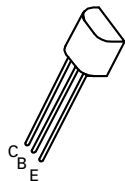
PNP SILICON PLANAR MEDIUM POWER
HIGH GAIN TRANSISTOR

ISSUE 1 - JANUARY 1997

ZTX1147A

FEATURES

- * $V_{CE0} = -12V$
- * 4 Amp Continuous Current
- * 20 Amp pulse Current
- * Low Saturation Voltage
- * High Gain



E-Line
TO92 Compatible

ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V_{CBO}	-15	V
Collector-Emitter Voltage	V_{CEO}	-12	V
Emitter-Base Voltage	V_{EBO}	-5	V
Peak Pulse Current	I_{CM}	-20	A
Continuous Collector Current	I_C	-4	A
Base Current	I_B	-500	mA
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}	1	W
Operating and Storage Temperature Range	$T_j:T_{stg}$	-55 to +200	$^{\circ}C$

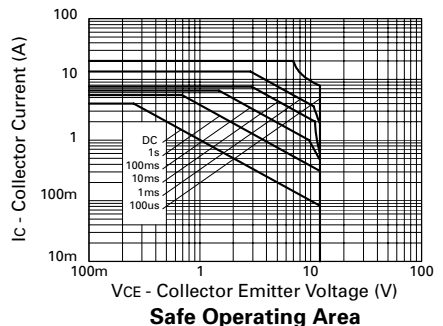
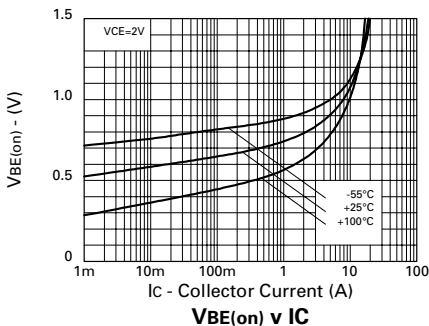
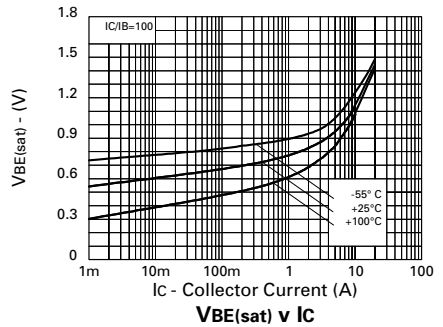
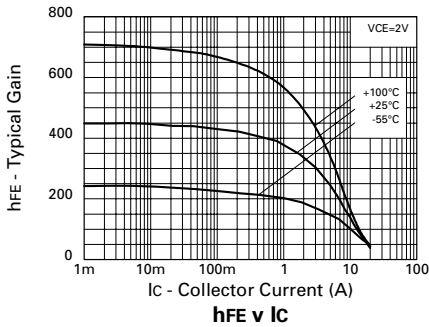
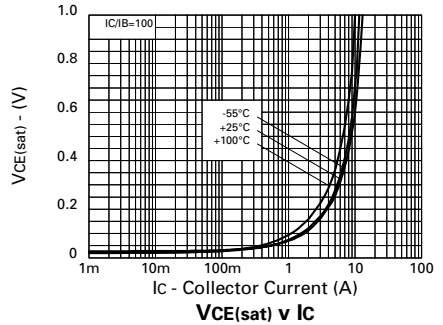
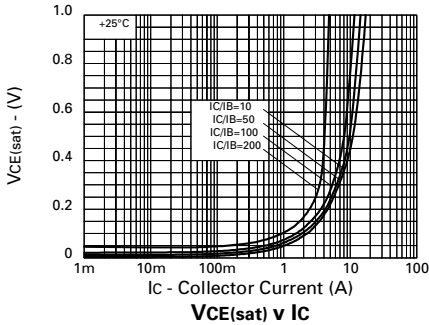
ZTX1147A

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

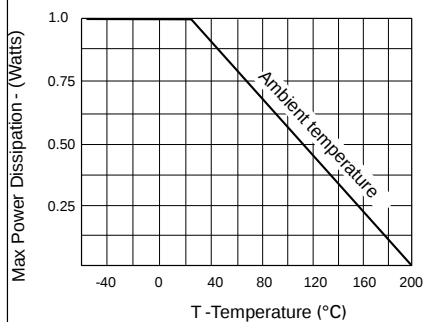
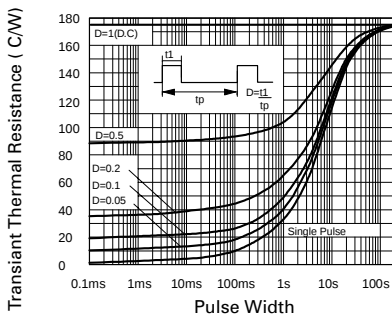
PARAMETER	SYMBOL	VALUE			UNIT	CONDITIONS.
		MIN.	TYP.	MAX.		
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-15	-35		V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CES}$	-12	-25		V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-12	-25		V	$I_C = -10\text{mA}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEV}$	-12	-25		V	$I_C = -100\mu\text{A}$, $V_{EB} = +1\text{V}$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	-8.5		V	$I_E = -100\mu\text{A}$
Collector Cut-Off Current	I_{CBO}		-0.3	-100	nA	$V_{CB} = -12\text{V}$
Emitter Cut-Off Current	I_{EBO}		-0.3	-100	nA	$V_{EB} = -4\text{V}$
Collector Emitter Cut-Off Current	I_{CES}		-0.3	-100	nA	$V_{CE} = -10\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-25	-50	mV	$I_C = -0.1\text{A}$, $I_B = -1\text{mA}^*$
			-70	-110	mV	$I_C = -0.5\text{A}$, $I_B = -2.5\text{mA}^*$
			-90	-130	mV	$I_C = -1\text{A}$, $I_B = -6\text{mA}^*$
			-115	-170	mV	$I_C = -2\text{A}$, $I_B = -20\text{mA}^*$
			-175	-235	mV	$I_C = -4\text{A}$, $I_B = -70\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-890	-1000	mV	$I_C = -4\text{A}$, $I_B = -70\text{mA}^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$		-830	-950	mV	$I_C = -4\text{A}$, $V_{CE} = -2\text{V}^*$
Static Forward Current Transfer Ratio	h_{FE}	270 250 200 170 90	450 400 340 270 150 50	850		$I_C = -10\text{mA}$, $V_{CE} = -2\text{V}^*$ $I_C = -0.5\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -2.0\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -4.0\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -10\text{A}$, $V_{CE} = -2\text{V}^*$ $I_C = -20\text{A}$, $V_{CE} = -2\text{V}^*$
Transition Frequency	f_T		115		MHz	$I_C = -50\text{mA}$, $V_{CE} = -10\text{V}$ $f = 50\text{MHz}$
Out Capacitance	C_{cb}		80		pF	$V_{CB} = -10\text{V}$, $f = 1\text{MHz}$
Switching Times	t_{on}		150		ns	$I_C = -4\text{A}$, $I_B = -40\text{mA}$, $V_{CC} = -10\text{V}$
	t_{off}		220		ns	$I_C = -4\text{A}$, $I_B = \pm 40\text{mA}$, $V_{CC} = -10\text{V}$

*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$

TYPICAL CHARACTERISTICS



ZTX1147A



SPICE PARAMETERS

* ZETEX ZTX1147 Spice model Last revision 10/12/96

*

.MODEL ZTX1147 PNP IS=1.272e-12 NF=0.989 ISE=2.5e-13 NE=1.65

+ BF=500 VAF=14.59 IKF=8 NR=1 ISC=8e-14 NC= 1.6

+ BR=90 VAR=3.1 IKR=1.2 RE=15e-3 RB=145e-3

+ RC=13e-3 CJE=560e-12

+ CJC=255e-12 VJC=0.6288

+ MJC=0.4048 TF=1.2e-9 TR=13e-9

*

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Zetex plc.

Fields New Road, Chadderton, Oldham, OL9-8NP, United Kingdom.

Telephone: (44)161 622 4422 (Sales), (44)161 622 4444 (General Enquiries)

Fax: (44)161 622 4420

Zetex GmbH
Streitfeldstraße 19
D-81673 München
Germany
Telefon: (49) 89 45 49 49 0
Fax: (49) 89 45 49 49 49

Zetex Inc.
47 Mall Drive, Unit 4
Commack NY 11725
USA
Telephone: (516) 543-7100
Fax: (516) 864-7630

Zetex (Asia) Ltd.
3510 Metroplaza, Tower 2
Hing Fong Road,
Kwai Fong, Hong Kong
Telephone: (852) 26100 611
Fax: (852) 24250 494

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

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moschip.ru_9